

Configurable Four Output, Low Jitter Crystal-less™ Clock Generator

Features

- Low RMS Phase Jitter: <1 ps (typ.)
- High Stability: ±25 ppm, ±50 ppm
- Wide Temperature Range:
- Industrial –40°C to +85°C
- Ext. Commercial -20°C to +70°C
- High Supply Noise Rejection: -50 dBc
- Four Format-Configurable Outputs:
 LVPECL, LVDS, HCSL, LVCMOS
- Available Pin-Selectable Frequency Table
- 1 Pin per Bank for 2 Frequency Sets
- Wide Frequency Range:
- 2.3 MHz 460 MHz
- 20-Pin QFN Footprint (5.0 mm x 3.2 mm)
- · Excellent Shock and Vibration Immunity
- · High Reliability
- 20x better MTF than quartz-based devices
- Wide Supply Range of 2.25V to 3.6V
- Lead Free and RoHS-Compliant
- · AEC-Q100 Automotive Qualified

Applications

- · Communications and Networks
- Ethernet
- 1G, 10GBASE-T/KR/LR/SR, and FCoE
- Storage Area Networks
 - SATA, SAS, Fibre Channel
- Passive Optical Networks
- EPON, 10G-EPON, GPON, 10G-PON
- HD/SD/SDI Video and Surveillance
- Automotive
- · Media and Video
- · Embedded and Industrial

General Description

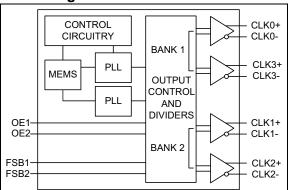
The DSC400 is a four output crystal-less[™] clock generator. It utilizes proven PureSilicon[™] MEMS technology to provide excellent jitter and stability while incorporating additional device functionality.

The nominal frequencies of the outputs can be identical or independently derived from common PLLs.

Each output may be configured independently to support a single-ended LVCMOS interface or a differential interface. Differential options include LVPECL, LVDS, or HCSL.

The DSC400 provides two independent select lines for choosing between two sets of pre-configured frequencies per bank. It also has two OE pins to allow for enabling and disabling outputs.

The DSC400 is packaged in a 20-pin QFN (5 mm x 3.2 mm) and is available in extended commercial and industrial temperature grades.



Block Diagram

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	–0.3V to +4.0V
Input Voltage	–0.3V to V _{DD} +0.3V
ESD Protection (HBM)	4 kV
ESD Protection (MM)	
ESD Protection (CDM)	

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Supply Voltage (Note 1)	V _{DD}	2.25	_	3.6	V	_
Core Supply Current (Note 2)	IDDCORE	—	40	44	mA	OE(1:2) = 0. All outputs disabled.
Frequency Stability	Δf	_	_	±25	ppm	All temperature and V _{DD}
				±50		ranges.
Aging - First Year	Δf_{Y1}	_		±5	ppm	One year at +25°C
Aging - After First Year	Δf_{Y2} +	—		<±1	ppm/yr	Year two and beyond at +25°C
Start-up Time (Note 3)	t _{SU}	_	_	5	ms	T = +25°C
Input Logic Levels	V _{IH}	0.75 x V _{DD}	_	—	V	Input logic high
	V _{IL}	_	_	0.25 x V _{DD}		Input logic low
Output Disable Time (Note 4)	t _{DA}	—	—	5	ns	OE(1:2) transition from 1 to 0
Output Enable Time (Note 4)	t _{EN}	—	—	20	ns	OE(1:2) transition from 0 to 1
Pull-Up Resistor	R _{PU}		40	_	kΩ	All input pins have an internal pull-up

Note 1: V_{DD} pins should be filtered with a 0.1 μ F capacitor connected between V_{DD} and V_{SS} .

2: The addition of I_{DDCORE} and I_{DDIO} provides the total current consumption of the device.

3: t_{SU} is time to 100 ppm stable output frequency after V_{DD} is applied and outputs are enabled.

4: See the Output Waveform section for more information.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Operating Temperature Bange (T)	T _A	-20	—	+70	°C	Ordering Option E
Operating Temperature Range (T)	T _A	-40	—	+85	°C	Ordering Option I
Junction Temperature	Τ _J	—	—	+150	°C	—
Storage Temperature Range	Τ _S	-40	—	+150	°C	—
Soldering Temperature		—	—	+260	°C	40 sec. max.

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature, and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

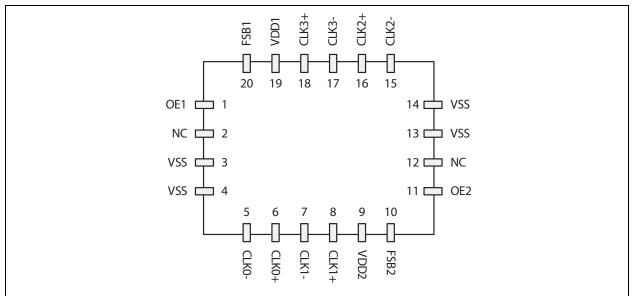


FIGURE 2-1: Pin Configuration, 20-Pin QFN (5.0 mm x 3.2 mm)

The descriptions of the pins are listed in Table 2-1.

Pin Number	Pin Name	Pin Type	Description
1	OE1	I	Output Enable for Bank1 (CLK0 and CLK3); Active-High. See Table 3-1.
2	NC	N/A	Leave unconnected or connect to ground.
3	V _{SS}	PWR	Ground.
4	V _{SS}	PWR	Ground.
5	CLK0–	0	Complement output of differential pair 0 (off when in LVCMOS format).
6	CLK0+	0	True output of differential pair 0 or LVCMOS output 0.
7	CLK1–	0	Complement output of differential pair 1 (off when in LVCMOS format).
8	CLK1+	0	True output of differential pair 1 or LVCMOS output 1.
9	V _{DD2}	PWR	Power Supply for Bank2 (CLK1 and CLK2).
10	FSB2	I	Input for selecting pre-configured frequencies on Bank2 (CLK1 and CLK2).
11	OE2	I	Output Enable for Bank2 (CLK1 and CLK2); Active-High. See Table 3-1.
12	NC	N/A	Leave unconnected or connect to ground.
13	V _{SS}	PWR	Ground.
14	V _{SS}	PWR	Ground.
15	CLK2–	0	Complement output of differential pair 2 (off when in LVCMOS format).
16	CLK2+	0	True output of differential pair 2 or LVCMOS output 2.
17	CLK3–	0	Complement output of differential pair 3 (off when in LVCMOS format).
18	CLK3+	0	True output of differential pair 3 or LVCMOS output 3.
19	V _{DD1}	PWR	Power Supply for Bank1 (CLK0 and CLK3).
20	FSB1	I	Input for selecting pre-configured frequencies on Bank1 (CLK0 and CLK3).

TABLE 2-1:PIN FUNCTION TABLE

3.0 OPERATIONAL DESCRIPTION

The DSC400 is a crystal-less[™] clock generator. Unlike older clock generators in the industry, it does not require an external crystal to operate; it relies on the integrated MEMS resonator that interfaces with internal PLLs. This technology enhances performance and reliability by allowing tighter frequency stability over a far wider temperature range. In addition, the higher resistance to shock and vibration decreases the aging rate to allow for much improved product life in the system.

3.1 Inputs

There are four input signals in the device. Each has an internal (40 k Ω) pull-up to default the selection to a high (1). Inputs can be controlled through hardware strapping method with a resistor to ground to assert the input low (0). Inputs may also be controlled by other components' GPIOs

In case more than one frequency set is desired, FSB1 and FSB2 are used to independently select one of two sets per bank. FSB1 selects the pre-configured set on Bank1 (CLK0 and CLK3) and FSB2 selects the pre-configured set on Bank2 (CLK1 and CLK2), as shown in Table 1-1 in the Product Identification System section.

If there is a requirement to disable outputs, the inputs OE1 and OE2 are used in conjunction to disable the banks of outputs. Outputs are disabled in tri-state (Hi-Z) mode. See Table 3-1 for more information.

TABLE 3-1: OUTPUT ENABLE SELECTION TABLE

OE1	OE2	Bank 1 (CLK0 & CLK3)	Bank 2 (CLK1 & CLK2)
0	0	Hi-Z	Hi-Z
0	1	Hi-Z	Running
1	0	Running	Hi-Z
1	1	Running	Running

3.2 Outputs

The four outputs are grouped into two banks. Each bank is supplied by an independent V_{DD} to allow for optimized noise isolation between the two banks. Each bank provides two synchronous outputs generated by a common PLL:

- Bank1 is composed of outputs CLK0 and CLK3.
- Bank2 is composed of outputs CLK1 and CLK2.

Each output may be pre-configured independently to be one of the following formats: LVCMOS, LVDS, LVPECL or HCSL. In case the output is configured to be single-ended LVCMOS, the frequency is generated on the true output (CLKx+) and the complement output (CLKx–) is shut off in a low state. Frequencies can be chosen from 2.3 MHz to 460 MHz for differential outputs and from 2.3 MHz to 170 MHz on LVCMOS outputs.

3.3 Power

 V_{DD1} and V_{DD2} supply the power to banks 1 and 2 respectively. Each V_{DD} may each have a different supply voltage from the other as long as it is within the 2.25V to 3.6V range. Each V_{DD} pin should have a 0.1 μF capacitor to filter high-frequency noise. V_{SS} is common to the entire device.

4.0 TERMINATION SCHEMES

4.1 LVPECL

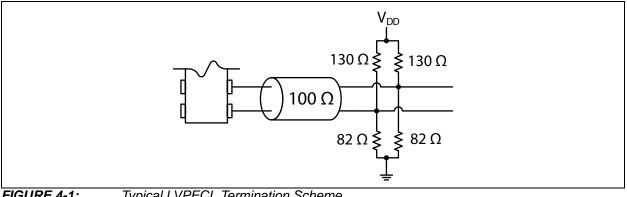


FIGURE 4-1:	Typical LVPECL	Termination Scheme.
-------------	----------------	---------------------

Parameter	Symbol	Min.	Тур.	Max.	Units	Condition
Output Logic	V _{OH}	V _{DD} – 1.08	_	_	V	Output Logic High, $R_L = 50\Omega$ to V_{DD} -2V
Levels	V _{OL}	—	_	V _{DD} – 1.55		Output Logic Low, $R_L = 50\Omega$ to V_{DD} -2V
Peak-to-Peak Output Swing		_	800	_	mV	Single-Ended
Output Transition Time	t _R	_	250	_	ps	Rise Time. 20% to 80%; R_L = 50 Ω to V_{DD} -2V
(Note 2)	t _F	_	250	—		Fall Time. 20% to 80%; R_L = 50 Ω to V_{DD} –2V
Frequency	f ₀	2.3	_	460	MHz	Single Frequency
Output Duty Cycle	SYM	48		52	%	Differential
IO Supply Current (Note 3)	I _{DDIO}	_	35	38	mA	Per Output at 125 MHz
Period Jitter (Note 4)	J_PER	_	2.5	—	ps _{RMS}	CLK(0:3) = 156.25 MHz
Integrated	J _{PH}	—	0.25	_	ps _{RMS}	200 kHz to 20 MHz @ 156.25 MHz
Phase Noise		_	0.38	_		100 kHz to 20 MHz @ 156.25 MHz
		_	1.7	2		12 kHz to 20 MHz @ 156.25 MHz

TABLE 4-1: LVPECL OUTPUTS (Note 1)

Note 1: LVPECL applicable to extended commercial temperature only.

2: See the Output Waveform section for more information.

3: The addition of I_{DDCORE} and I_{DDIO} provides the total current consumption of the device.

4: Period jitter includes crosstalk from adjacent output.

4.2 LVDS

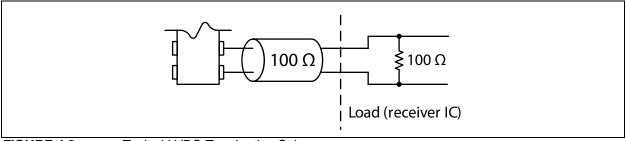


FIGURE 4-2: Typical LVDS Termination Scheme.

If the 100Ω clamping resistor does not exist inside the receiving device, it should be added externally on the PCB and placed as close as possible to the receiver.

Parameter	Symbol	Min.	Тур.	Max.	Units	Condition
Output Offset Voltage	V _{OS}	1.125	_	1.4	V	R = 100Ω Differential
Delta Offset Voltage	ΔV_{OS}	—	—	50	mV	—
Peak-to-Peak Output Swing	V _{PP}	_	350	_	mV	Single-Ended
Output Transition Time	t _R	_	200	_	ps	Rise Time, 20% to 80%, R _L = 50 Ω , C _L = 2 pF
(Note 1)	t _F	_	200	_		Fall Time, 20% to 80%, R_L = 50 Ω , C_L = 2 pF
Frequency	f ₀	2.3	_	460	MHz	Single Frequency
Output Duty Cycle	SYM	48	—	52	%	Differential
IO Supply Current (Note 2)	I _{DDIO}	—	9	12	mA	Per Output at 125 MHz.
Period Jitter	J _{PER}	_	2.5	_	ps _{RMS}	—
Integrated	J _{PH}	—	0.28	_	ps _{RMS}	200 kHz to 20 MHz @ 156.25 MHz
Phase Noise		_	0.4	_		100 kHz to 20 MHz @ 156.25 MHz
Note 4. Coo th		_	1.7	2.0		12 kHz to 20 MHz @156.25 MHz

TABLE 4-2: LVDS OUTPUTS

Note 1: See the Output Waveform section for more information.

2: The addition of I_{DDCORE} and I_{DDIO} provides the total current consumption of the device.

4.3 HCSL

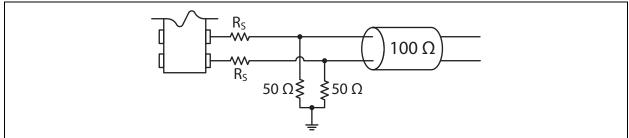


FIGURE 4-3: Typical HCSL Termination Scheme.

 R_S is a series resistor implemented to match the trace impedance. Depending on the board layout, the value may range from 0 Ω to 30 Ω .

Parameter	Symbol	Min.	Тур.	Max.	Units	Condition
Output Logic	V _{OH}	0.725	—		V	Output Logic High, $R_L = 50\Omega$
Levels	V _{OL}	_	_	0.1		Output Logic Low, $R_L = 50\Omega$
Peak-to-Peak Output Swing	—	—	750		mV	Single-Ended
Output Transition Time	t _R	200	—	400	ps	Rise Time, 20% to 80%, R _L = 50 Ω , C _L = 2 pF
(Note 1)	t _F	200	—	400		Fall Time, 20% to 80%, R_L = 50 Ω , C_L = 2 pF
Frequency	f ₀	2.3	—	460	MHz	Single Frequency
Output Duty Cycle	SYM	48	—	52	%	Differential
IO Supply Current (Note 2)	I _{DDIO}	—	20	22	mA	Per Output at 125 MHz.
Period Jitter	J _{PER}	_	2.5	-	ps _{RMS}	—
Integrated	J _{PH}		0.25		ps _{RMS}	200 kHz to 20 MHz @ 156.25 MHz
Phase Noise			0.37			100 kHz to 20 MHz @ 156.25 MHz
Note 4: Coo th		_	1.7	2.0		12 kHz to 20 MHz @156.25 MHz

TABLE 4-3: HCSL OUTPUTS

Note 1: See the Output Waveform section for more information.

2: The addition of I_{DDCORE} and I_{DDIO} provides the total current consumption of the device.

4.4 LVCMOS

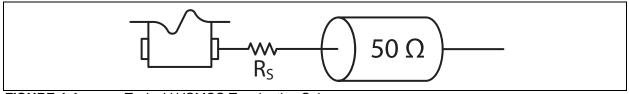


FIGURE 4-4: Typical LVCMOS Termination Scheme.

 R_S is a series resistor implemented to match the trace impedance to that of the clock output. Depending on the board layout, the value may range from 0 Ω to 27 Ω .

Parameter	Symbol	Min.	Тур.	Max.	Units	Condition
Output Logic	V _{OH}	0.9 x V _{DD}	_	_	V	Output Logic High, I = $\pm 6 \text{ mA}$
Levels	V _{OL}	-	_	0.1 x V _{DD}		Output Logic Low, I = ±6 mA
Output	t _R	-	1.1	2.0	ns	Rise Time, 20% to 80%, C _L = 15 pF
Transition Time (Note 1)	t _F	_	1.3	2.0		Fall Time, 20% to 80%, C _L = 15 pF
Frequency	f ₀	2.3	_	170	MHz	All Temperature Ranges, Except Automotive
		_	_	100		Automotive Temperature Range
Output Duty Cycle	SYM	44	_	55	%	_
IO Supply Current (Note 2)	I _{DDIO}	—	11	14	mA	Per Output at 125 MHz, C _L = 15 pF
Period Jitter	J _{PER}	_	3	_	ps _{RMS}	CLK(0:3) = 125 MHz
Integrated	J _{PH}	_	0.3	_	ps _{RMS}	200 kHz to 20 MHz @ 125 MHz
Phase Noise			0.38	_]	100 kHz to 20 MHz @ 125 MHz
			1.7	2.0		12 kHz to 20 MHz @125 MHz

TABLE 4-4: LVCMOS OUTPUTS

Note 1: See the Output Waveform section for more information.

2: The addition of I_{DDCORE} and I_{DDIO} provides the total current consumption of the device.

5.0 OUTPUT WAVEFORM

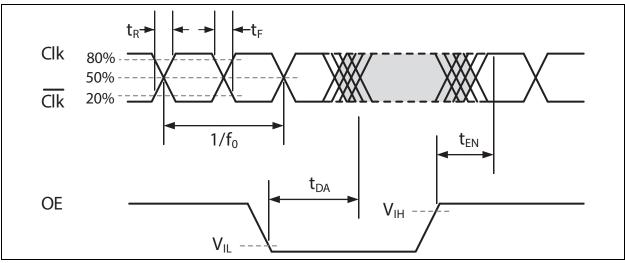
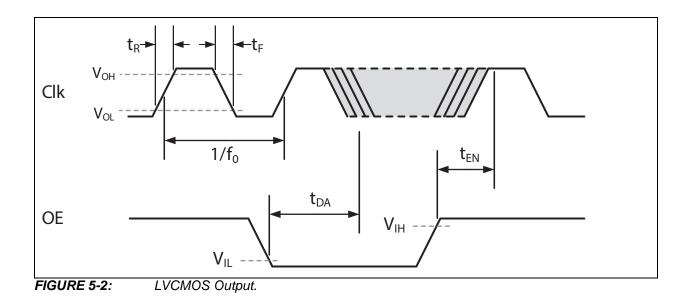
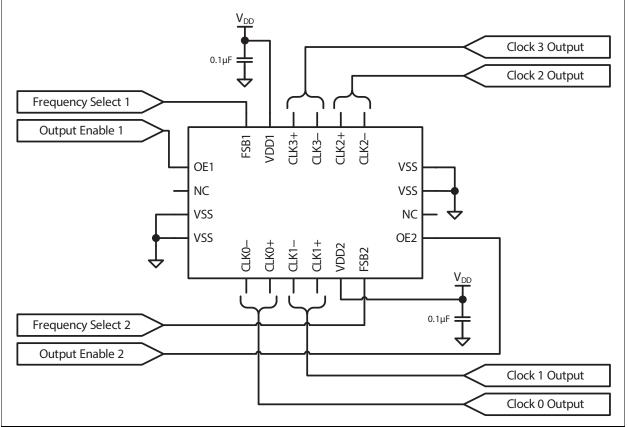


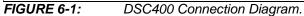
FIGURE 5-1: Differential Output (LVDS, LVPECL, HCSL).



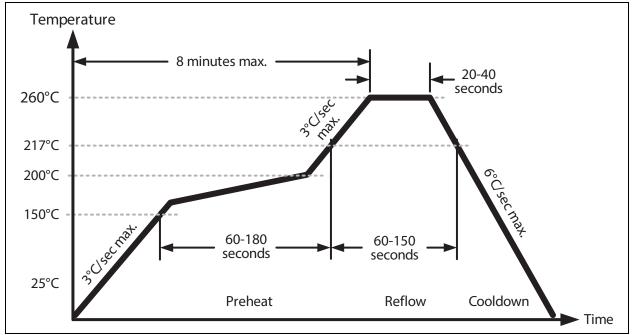
6.0 CONNECTION DIAGRAM

The connection diagram below includes recommended capacitors to be placed on each V_{DD} for noise filtering.





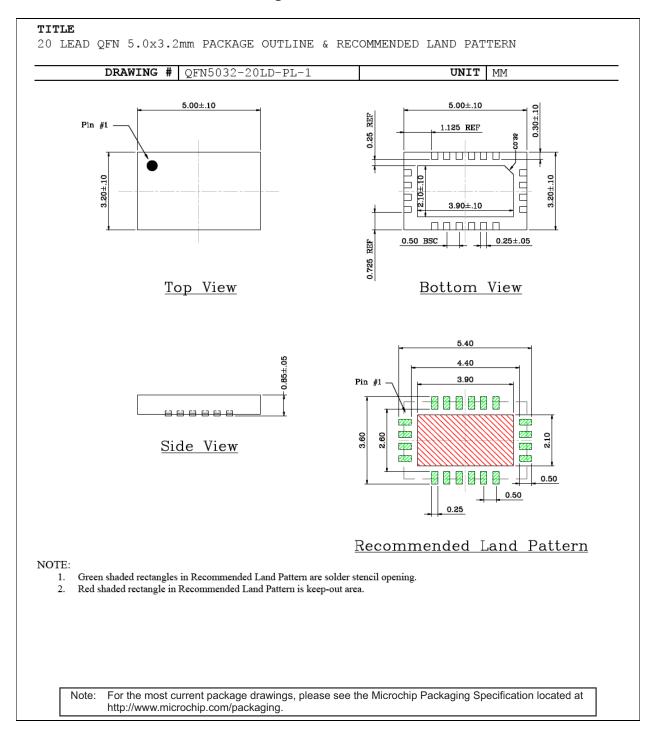
7.0 SOLDER REFLOW PROFILE



MSL 1 @ 260°C refer to JSTD-020C					
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec. max.				
Preheat Time 150°C to 200°C	60-180 sec.				
Time Maintained above 217°C	60-150 sec.				
Peak Temperature	255°C to 260°C				
Time within 5°C of Actual Peak	20-40 sec.				
Ramp-Down Rate	6°C/sec. max.				
Time 25°C to Peak Temperature	8 minutes max.				

8.0 PACKAGE MARKING INFORMATION

20-Lead QFN 5.0 mm x 3.2 mm Package Outline and Recommended Land Pattern



NOTES:

APPENDIX A: REVISION HISTORY

Revision A (September 2016)

- Converted Micrel data sheet DSC400 to Microchip DS20005612A.
- Minor text changes throughout.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

	v			v			
$\frac{\text{PART NO.}}{1} - \frac{X}{1}$				X X	Ĭ		× T
Output	Outpu		LK1 CLK0 Freq Pac utput Output Code ormat Format	kage Temp. Range	Stabil	ity Pac	sking
Device:				h Low littor		Exa	mples:
Device:	DSC40	<i>J</i> U.	Configurable Four Output, Low Jitter Crystal-less Clock Generator			a)	DSC400-2143QxxxxKE1T: Configurable Four Output, Low Jitter Crystal-less
CLK3 Output Format:	0 1 2 3 4	= = = =					Clock Generator; LVPECL CLK3; LVCMOS CLK2; HCSL CLK1; LVDS CLK0; Frequency Code; 20-Pin QFN; –20°C to +70°C Temp. Range; ±50 ppm Stabil- ity; Tape & Reel
CLK2 Output Format:	1 2 3 4	= = =	HCSL			b)	DSC400-4132QxxxxKl2T: Configurable Four Output, Low Jitter Crystal-less Clock Generator; HCSL CLK3; LVCMOS CLK2; LVDS CLK1; LVPECL CLK0; Frequency Code; 20- Pin QFN; -40°C to +85°C Temp. Range; ±25 ppm Stability; Tape & Reel
CLK1 Output Format:	0 1 2	= = =	OFF LVCMOS LVPECL				
	3 4	=	LVDS HCSL			c)	DSC400-0202QxxxxKE2T: Configurable Four Output, Low Jitter Crystal-less Clock Generator; OFF CLK3; LVPECL CLK2; OFF
CLK0 Output Format:	1 2 3 4	= = =	20. 202				CLK1; LVPECL CLK0; Frequency Code; 20-Pin QFN; –20°C to +70°C Temp. Range; ±25 ppm Stability; Tape & Reel
Frequency Code:	Qxxxx	=	This code is assigned by th table in this section for mor		the	d)	DSC400-1111QxxxxKI1T: Configurable Four Output, Low Jitter Crystal-less Clock Generator; LVCMOS CLK3 through CLK0;
Package:	К	=	20-Pin QFN				Frequency Code; 20-Pin QFN; -40°C to +85°C Temp. Range; ±50 ppm Stability; Tape & Reel
Temperature Range:	E I	= =	–20°C to +70°C –40°C to +85°C				
Stability:	1 2	= =	±50 ppm ±25 ppm				
Packing:	т	=	Tape & Reel				

1.0 FACTORY CONFIGURATION CODE ASSIGNMENT OF QXXXX

The DSC400 is meant for customers to define their own frequency requirements at the four available outputs. The Qxxxx number identifies these specific customer requirements and is assigned by the factory.

TABLE 1-1: EXAMPLE OF HOW FSB1 & FSB2 ARE APPLIED & THE QXXXX ASSIGNMENT

Bank1	Quitmuito	FSI	Qxxxx Number		
	Outputs	1 (default)	0		
Daliki	CLK0	125 MHz	150 MHz		
	CLK3	50 MHz	25 MHz	1	
	Outputs	FSI	Q0001		
Bank2	Outputs	1 (default)	0		
Dalikz	CLK1	156.25 MHz	100 MHz		
	CLK2	156.25 MHz	100 MHz		

© 2016 Microchip Technology Inc.

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, AnyRate, dsPIC, FlashFlex, flexPWR, Heldo, JukeBlox, KeeLoq, KeeLoq logo, Kleer, LANCheck, LINK MD, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC32 logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

ClockWorks, The Embedded Control Solutions Company, ETHERSYNCH, Hyper Speed Control, HyperLight Load, IntelliMOS, mTouch, Precision Edge, and QUIET-WIRE are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet logo, MiWi, motorBench, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PureSilicon, RightTouch logo, REAL ICE, Ripple Blocker, Serial Quad I/O, SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2016, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-5224-0985-4



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

Cleveland Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110

Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078

ASIA/PACIFIC

Asia Pacific Office Suites 3707-14, 37th Floor Tower 6, The Gateway

Harbour City, Kowloon Hong Kong Tel: 852-2943-5100 Fax: 852-2401-3431

Australia - Sydney Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115 Fax: 86-571-8792-8116

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

Fax: 852-2401-3431

China - Qingdao Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian Tel: 86-29-8833-7252 Fax: 86-29-8833-7256 ASIA/PACIFIC

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

India - Bangalore Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune Tel: 91-20-3019-1500

Japan - Osaka Tel: 81-6-6152-7160 Fax: 81-6-6152-9310

Japan - Tokyo Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7828

Taiwan - Taipei Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351

Fax: 66-2-694-1350

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Dusseldorf Tel: 49-2129-3766400

Germany - Karlsruhe Tel: 49-721-625370

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Venice Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Poland - Warsaw Tel: 48-22-3325737

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820

06/23/16